OBSOLETE



LM3590

SNVS258B-NOVEMBER 2003-REVISED APRIL 2013

LM3590 Series White LED Driver

Check for Samples: LM3590

FEATURES

www.ti.com

- Drives up to 3 Stacked White LEDs
- 6.0V-12.6V Input Voltage Range
- Up to 20mA LED Output Current
- Excellent LED Current Matching Specified by Series Configuration
- Single Connection to the White LEDs in the Display Module
- Tightly Controlled Programmable Current Source
- Low Shutdown Current (0.1µA typ.)
- PWM Brightness Control
- Very Small Solution Size
- SOT-23-5 Package: 3mm × 3mm × 1.0mm (L×W×H)

APPLICATIONS

- White LED Display Backlights
- Keypad Backlights
- General Purpose Constant Current Driver for High Forward-voltage LEDs

Typical Application Circuit

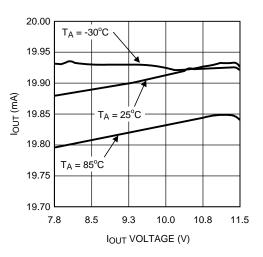
DESCRIPTION

The LM3590 is a White LED constant current driver capable of supplying up to 3 White LEDs connected in series with 20mA. This device operates over a wide 6V-12.6V input voltage range. The output can accomodate LEDs with a combined forward voltage of up to 11.5V, from a 12V input supply. The LED drive current is programmed by using an external resistor on the I_{SET} pin.

LED brightness can be linearly varied up to the programmed LED current by applying a Pulse Width Modulated (PWM) signal to the EN pin of the device. The LED output current of the LM3590 is tightly controlled over temperature and voltage. LED Current matching is ensured due to the series configuration of the LEDs. The series topology also simplifies the connection between the White LEDs in the display module and the LM3590 since only one connection is required.

The LM3590 typically draws only $50\mu A$ when operating in the no-load condition and draws less than $0.1\mu A$ when the device is shut down.

The LM3590 is available in a small 5-pin SOT-23 package.



VIN = 6V - 12V $V_{IN} = 6V - 12V$ V_{IN} IOUT I_{OUT} I_{OUT}

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. All trademarks are the property of their respective owners.

LM3590

TEXAS INSTRUMENTS

www.ti.com

SNVS258B-NOVEMBER 2003-REVISED APRIL 2013

Connection Diagram

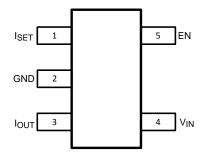


Figure 1. Top View

PIN DESCRIPTIONS

Pin #	Name	Function	
1	I _{SET}	Programmable LED current Input. The LED current has the following relationship with the resistor used: R _{SET} = 100 × (125 \div I _{OUT})	
2	GND	Ground Connection	
3	I _{OUT}	Constant Current LED Output	
4	V _{IN}	Power Supply Voltage Input. Input voltage range: 6V-12.6V	
5	EN	Device Enable	



SNVS258B-NOVEMBER 2003-REVISED APRIL 2013



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾⁽²⁾⁽³⁾

V _{IN}	-0.3 to 13.0V Max		
EN	-0.3 to (V _{IN} +0.3V) w/ 13.0V max		
Maximum Junction Temperature, T _{JMAX}	150°C		
Storge Temperature	−65°C to +150°C		
Maximum Lead Temperature (Soldering, 5 sec	260°C		
ESD Rating ⁽⁴⁾	Human Body Model	1.5kV	
	Machine Model	200V	

(1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings are conditions under which operation of the device is specified. Operating Ratings do not imply ensured performance limits. For ensured performance limits and associated test conditions, see the Electrical Characteristics table.

(2) All voltages are with respect to the potential at the GND pin.
(3) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/Distributors for availability and specifications.

(4) The human-body model is a 100pF capacitor discharged through a 1.5kΩ resistor into each pin. The machine model is a 220pF capacitor discharged directly into each pin.

OPERATING CONDITIONS

Input Voltage Range	6.0V to 12.6V
EN Voltage Range	0V to V _{IN}
Ambient Temperature (T _A) Range	−40°C to +85°C
Junction Temperature (T _J) Range	-40°C to +110°C

(1) Maximum ambient temperature (T_{A-MAX}) is dependent on the maximum operating junction temperature (T_{J-MAX-OP} = 110°C), the maximum power dissipation of the device in the application (P_{D-MAX}), and the junction-to-ambient thermal resistance of the part/package in the application (θ_{JA}), as given by the following equation: T_{A-MAX} = T_{J-MAX-OP} - (θ_{JA} x P_{D-MAX}). The ambient temperature operating rating is provided merely for convenience. This part may be operated outside the listed T_A rating, so long as the junction temperature of the device does not exceed the maximum operating rating of 110°C.

THERMAL INFORMATION

Junction-to-Ambient Thermal Resistance, SOT-23-5 Package $(\theta_{JA})^{(1)}$	220°C/W
--	---------

(1) Junction-to-ambient thermal resistance is highly application and board-layout dependent. In applications where high maximum power dissipation exists, special care must be paid to thermal dissipation issues. For more information on these topics, please refer to the Power Dissipation section of this datasheet.



SNVS258B-NOVEMBER 2003-REVISED APRIL 2013

www.ti.com

ELECTRICAL CHARACTERISTICS⁽¹⁾⁽²⁾

Limits in standard typeface are for $T_J = 25^{\circ}$ C and limits in **boldface** type apply over the full Operating Junction Temperature Range (-40°C $\leq T_J \leq +110^{\circ}$ C). Unless otherwise specified, $C_{IN} = 1 \ \mu$ F, $V_{IN} = 12.0$ V, $V_{EN} = 3.0$ V, $R_{SET} = 6.19$ k Ω , $V_{IOUT} = 10.8$ V.

Symbol	Parameter	Conditions	Min	Тур	Max	Units	
I _{OUT}	Output Current Capability	V _{IN} = 12V 7.5V ≤ V _{IOUT} ≤ 11.5V	19 (-5%)	20	21 (+5%)		
		$V_{IOUT} = 10.8V$ 11.3V $\leq V_{IN} \leq 12.6V$	19 (-5%)	20	21 (+5%)	mA	
		$R_{SET} = 8.35 k\Omega$		15			
		$R_{SET} = 12.5 k\Omega$		10			
	Output Current Programming			125 ÷ R _{SET}		А	
	I _{OUT} ratio to I _{SET}			100:1			
l _Q	Quiescent Supply Current	$\begin{array}{l} 11.3V \leq V_{\text{IN}} \leq 12.6V \\ R_{\text{SET}} = OPEN \\ I_{\text{OUT}} = OPEN \end{array}$		50	75	μA	
I _{SD}	Shutdown Supply Current	$V_{IN} = 12.6V$ $V_{EN} = 0V$		0.1	1	μΑ	
VISET	I _{SET} Reference Voltage			1.25		V	
V _{HR}	Minimum Current Source Voltage Headroom $(V_{IN} - V_{IOUT})^{(3)}$	I _{OUT} = 95% nominal		300		mV	
V _{IH}	Logic Input EN: High level		1.1		V _{IN}	V	
V _{IL}	Logic Input EN: Low level		0		0.3	V	
I _{EN}	Enable Pin Input Current ⁽⁴⁾			6		μA	
t _{ON}	Turn-On Time	I _{OUT} = 90% of steady state		50		μs	

(1) All voltages are with respect to the potential at the GND pin.

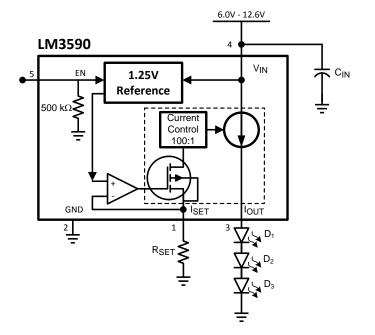
(2) All room temperature limits are 100% tested or specified through statistical analysis. All limits at temperature extremes are specified by correlation using standard Statistical Quality Control methods (SQC). All limits are used to calculate Average Outgoing Quality Level (AOQL). Typical numbers are not ensured, but do represent the most likely norm.

(3) The current source is connected internally between V_{IN} and V_{IOUT}. The voltage across the current source, [V_{IN} - V_{IOUT}], is referred to as headroom voltage. For the current source to regulate properly, a minimum headroom voltage must be present across it. Minimum required headroom voltage is proportional to the current flowing through the current source, as dictated by this equation: V_{HR-MIN} = 300mV × (I_{OUT} ÷ 20mA).

(4) An internal $500k\Omega$ pull-down resistor is connected between the EN and GND pins.

SNVS258B-NOVEMBER 2003-REVISED APRIL 2013

FUNCTIONAL BLOCK DIAGRAM



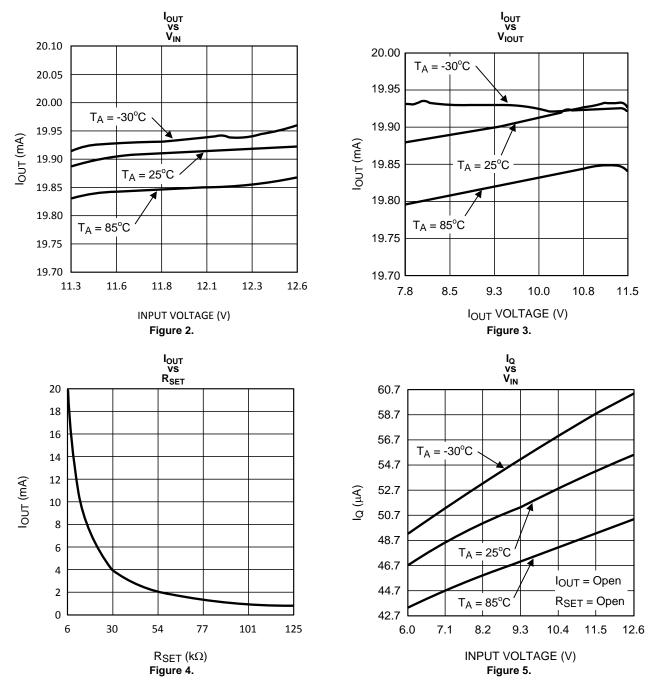
TEXAS INSTRUMENTS

www.ti.com

SNVS258B-NOVEMBER 2003-REVISED APRIL 2013

TYPICAL PERFORMANCE CHARACTERISTICS

Unless otherwise specified, $C_{IN} = 1\mu F$, $V_{IN} = 12.0V$, $V_{EN} = 3.0V$, $V_{IOUT} = 10.8V$, $R_{SET} = 6.19k\Omega$, $T_A = 25^{\circ}C$. C_{IN} is a low ESR multi-layer ceramic capacitor (MLCC).

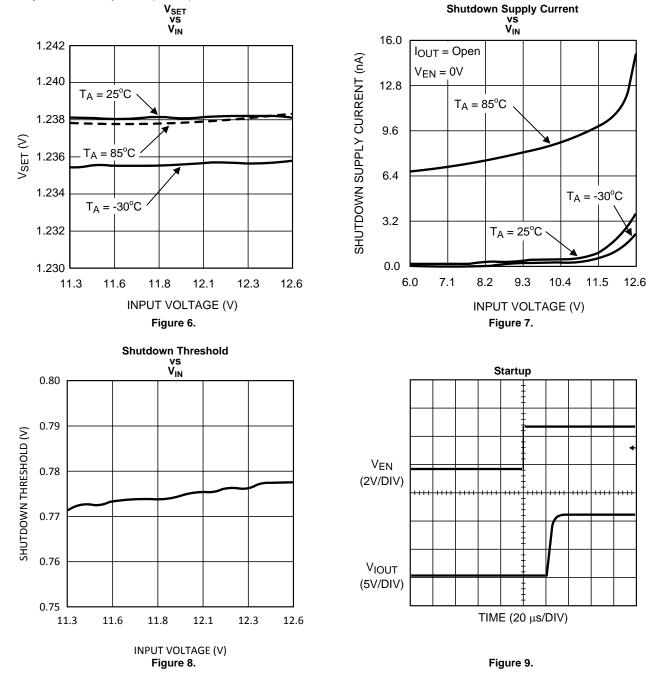




SNVS258B-NOVEMBER 2003-REVISED APRIL 2013

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

Unless otherwise specified, $C_{IN} = 1\mu$ F, $V_{IN} = 12.0$ V, $V_{EN} = 3.0$ V, $V_{IOUT} = 10.8$ V, $R_{SET} = 6.19$ k Ω , $T_A = 25^{\circ}$ C. C_{IN} is a low ESR multi-layer ceramic capacitor (MLCC).





SNVS258B-NOVEMBER 2003-REVISED APRIL 2013

www.ti.com

APPLICATION INFORMATION

CIRCUIT DESCRIPTION

The LM3590 is a constant current series White-LED Driver, providing up to 20mA from an input voltage between 7.5V to 12.6V. To set the LED drive current, the LM3590 uses a resistor connected to the I_{SET} pin to set a reference current. This reference current is then multiplied and mirrored to the constant current output, I_{OUT} . The LED brightness can be controlled by applying a PWM (Pulse Width Modulation) signal to the Enable pin (EN). (see PWM BRIGHTNESS CONTROL PROCEDURES section).

ENABLE MODE

The Enable pin (EN) disables the part and reduces the quiescent current to 0.1μ A (typ.). The LM3590 has an active-high enable pin (LOW = shut down, HIGH = operating). The LM3590 EN pin can be driven with a low-voltage CMOS logic signal (1.5V logic, 1.8V logic, etc). There is an internal 500k Ω pull-down between the EN and GND pins of the LM3590.

CAPACITOR SELECTION

Although not required for normal operation, a capacitor can be added to the voltage input of the LM3590 to reduce line noise. A surface-mount multi-layer ceramic capacitor (MLCC) is recommended. MLCCs are small, inexpensive and have very low equivalent series resistance (ESR, $\leq 15m\Omega$ typ.). MLCCs with a X5R or X7R temperature characteristic are preferred for use with the LM3590. Table 1 lists suggested capacitor suppliers for the typical application circuit.

Table 1. Ceramic Capacitor Manufacturers

Manufacturer	Contact	
ТДК	www.component.tdk.com	
Murata	www.murata.com	
Taiyo Yuden	www.t-yuden.com	

LED SELECTION

The LM3590 is designed to drive up to 3 LEDs with the combined forward voltages of the LEDs being no greater than 11.5V, when using a 12V input supply. The typical and maximum diode forward voltage depends highly on the manufacturer and their technology. Table 2 lists two suggested manufacturers. LED Forward current matching is specified by design, due to the series LED configuration of the LM3590.

Table 2. White LED Selection

Manufacturer	Contact	
Osram	www.osram-os.com	
Nichia	www.nichia.com	

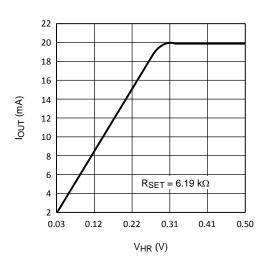
LED HEADROOM VOLTAGE (V_{HR})

A single current source is connected internally between V_{IN} and I_{OUT} . The voltage across the current source, $(V_{IN} - V_{IOUT})$, is referred to as headroom voltage (V_{HR}) . The current source requires a sufficient amount of headroom voltage to be present across it in order to regulate properly. Minimum required headroom voltage is proportional to the current flowing through the current source, as dictated by the equation:

 $V_{HR-MIN} = k_{HR} \times I_{OUT}$

The parameter k_{HR} , typically 15mV/mA in the LM3590, is a proportionality constant that represents the ONresistance of the internal current mirror transistors. For worst-case design calculations, using a k_{HR} of 20mV/mA is recommended. (Worst-case recommendation accounts for parameter shifts from part-to-part variation and applies over the full operating temperature range). Figure 10 shows how output current of the LM3590 varies with respect to headroom voltage.





 $V_{HR} = V_{IN} - V_{IOUT}$ $V_{IN} = 12.0V$

Figure 10. I_{OUT} vs V_{HR}

On the flat part of the graph, the current is regulated properly as there is sufficient headroom voltage for regulation. On the sloping part of the graph the headroom voltage is too small, the current source is squeezed, and the current drive capability is limited. Thus, operating the LM3590 with insufficient headroom voltage across the current source should be avoided.

I_{SET} PIN

An external resistor, R_{SET} , connected to the I_{SET} pin sets the output current. The internal current mirror sets the series LED output current with a 100:1 ratio to the current through R_{SET} . The current matching through each LED is ensured by the series LED drive topology. The following equation approximates the LED current:

 $I_{OUT} = 100 \times (1.25V \div R_{SET})$ (Amps)

PWM BRIGHTNESS CONTROL PROCEDURES

The brightness of the LEDs can be linearly varied from zero up to the maximum programmed current level by applying a Pulse-Width-Modulated signal to the EN pin of the LM3590. The following procedures illustrate how to program the LED drive current and adjust the output current level using a PWM signal.

- 1. Determine the maximum desired I_{OUT} current. Use the I_{OUT} equation to calculate R_{SET}
- Brightness control can be implemented by pulsing a signal at the EN pin. LED brightness is proportional to the duty cycle (D) of the PWM signal. For linear brightness control over the full duty cycle adjustment range, the PWM frequency (f) should be limited to accommodate the turn-on time (T_{ON} = 50µs) of the device.

 $D \times (1/f) > T_{ON}$

 $f_{MAX} = D_{MIN} \div T_{ON}$

If the PWM frequency is much less than 100Hz, flicker may be seen in the LEDs. For the LM3590, zero duty cycle will turn off the LEDs and a 50% duty cycle will result in an average I_{OUT} being half of the programmed LED current. For example, if R_{SET} is set to program 15mA, a 50% duty cycle will result in an average I_{LED} of 7.5mA.



SNVS258B-NOVEMBER 2003-REVISED APRIL 2013

POWER DISSIPATION

The power dissipation ($P_{DISSIPATION}$) and junction temperature (T_J) can be approximated with the equations below. P_{IN} is the product of the input current and input voltage, P_{IOUT} is the power consumed by the LEDs, T_A is the ambient temperature, and θ_{JA} is the junction-to-ambient thermal resistance for the SOT23-5 package. V_{IN} is the input voltage to the LM3590, V_{IOUT} is the sum of the forward voltages of LEDs connected to the I_{OUT} pin, and I_{OUT} is the programmed LED current.

$$\begin{split} & \mathsf{P}_{\mathsf{DISSIPATION}} = \mathsf{P}_{\mathsf{IN}} - \mathsf{P}_{\mathsf{IOUT}} \\ & = (\mathsf{V}_{\mathsf{IN}} \times \mathsf{I}_{\mathsf{OUT}}) - (\mathsf{V}_{\mathsf{IOUT}} \times \mathsf{I}_{\mathsf{OUT}}) \\ & \mathsf{T}_{\mathsf{J}} = \mathsf{T}_{\mathsf{A}} + (\mathsf{P}_{\mathsf{DISSIPATION}} \times \theta_{\mathsf{JA}}) \end{split}$$

The junction temperature rating takes precedence over the ambient temperature rating. The LM3590 may be operated outside the ambient temperature rating, so long as the junction temperature of the device does not exceed the maximum operating rating of 110°C. The maximum ambient temperature rating must be derated in applications where high power dissipation and/or poor thermal resistance causes the junction temperature to exceed 110°C.

Application Circuits

Figure 11 shows how to program the LED current to four different DC levels using two digital logic signals. The programmed LED current is a function of the equivalent resistance on the I_{SET} pin (R_{ISET}), resulting from the logic signals on SET1 and SET2. Example values for R1, R2, and RSET an the resulting 4 current levels are shown below.

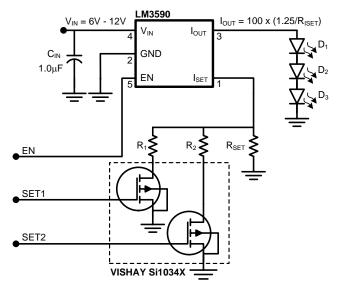


Figure 11. Example: $R_1 = 15.8k\Omega$, $R_2 = 31.6k\Omega$, $R_{SET} = 31.6k\Omega$

			0	0 0	
EN	SET1	SET2	R _{ISET}	Example R _{ISET}	Example I _{OUT}
0	Х	Х	Shutdown	Shutdown	Shutdown
1	1	1	$R_{SET} \ R_1 \ R_2$	31.6kΩ∥15.kΩ∥31.6kΩ	16mA
1	1	0	R _{SET} ∥R₁	31.6kΩ∥15.kΩ	12mA
1	0	1	R _{SET} ∥R ₂	31.6kΩ∥31.6kΩ	8mA
1	0	0	R _{SET}	31.6kΩ	4mA

Table 3. Digital LED Current Programming



SNVS258B-NOVEMBER 2003-REVISED APRIL 2013

REVISION HISTORY

Ch	nanges from Revision A (April 2013) to Revision B P	age
•	Changed layout of National Data Sheet to TI format	10

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products		Applications	
Audio	www.ti.com/audio	Automotive and Transportation	www.ti.com/automotive
Amplifiers	amplifier.ti.com	Communications and Telecom	www.ti.com/communications
Data Converters	dataconverter.ti.com	Computers and Peripherals	www.ti.com/computers
DLP® Products	www.dlp.com	Consumer Electronics	www.ti.com/consumer-apps
DSP	dsp.ti.com	Energy and Lighting	www.ti.com/energy
Clocks and Timers	www.ti.com/clocks	Industrial	www.ti.com/industrial
Interface	interface.ti.com	Medical	www.ti.com/medical
Logic	logic.ti.com	Security	www.ti.com/security
Power Mgmt	power.ti.com	Space, Avionics and Defense	www.ti.com/space-avionics-defense
Microcontrollers	microcontroller.ti.com	Video and Imaging	www.ti.com/video
RFID	www.ti-rfid.com		
OMAP Applications Processors	www.ti.com/omap	TI E2E Community	e2e.ti.com
Wireless Connectivity	www.ti.com/wirelessconne	ectivity	

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2013, Texas Instruments Incorporated